

### DESCRIPTION

The MP1906 is a high-performance, 80V, gate driver that can drive two external N-MOSFETs in a half-bridge configuration with a 12V gate supply. It accepts independent gate input signals and provides shoot-through prevention. During under-voltage lockout, the output of the high- and low-side drivers goes low to prevent erratic operation under low supply conditions.

The high-current driving capability and short dead time make it suitable for high-power and high-efficiency power applications, such as telecom DC-DC converters. The compact 8-pin SOIC package minimizes the component count and the board space.

### FEATURES

- Drives Two Low-Cost, High-Efficiency N-MOSFETs
- 10V-16V Gate Drive Supply
- 3.3V, 5V Logic Compatibility
- 80ns Propagation Delay
- Less than 90 $\mu$ A Quiescent Current
- Under-Voltage Lockout for Both Channels
- Input-Signal-Overlap Protection
- Internal 150ns Dead Time
- Available in a Compact 8-pin SOIC Package

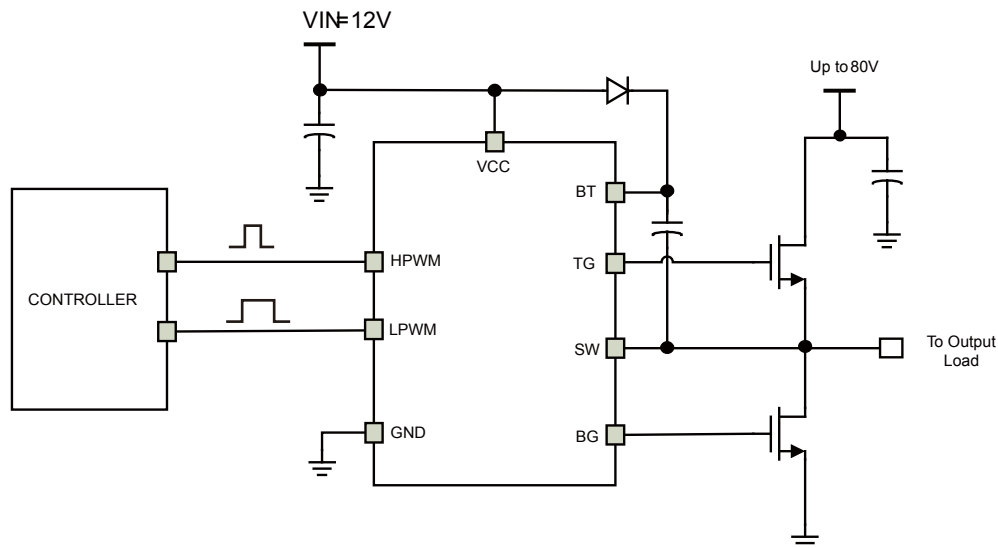
### APPLICATIONS

- Motor Drivers
- Half-Bridge Power Supplies
- Avionics DC-DC Converters
- Active-Clamp Forward Converters

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### TYPICAL APPLICATION

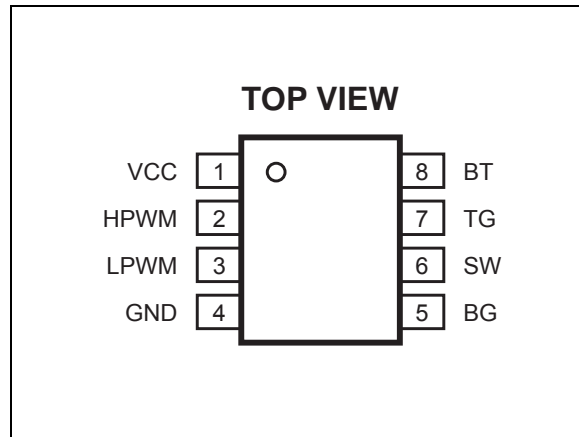


## ORDERING INFORMATION

Part Number*	Package	Top Marking
MP1906DS	SOIC8	MP1906

\*For Tape & Reel, add suffix -Z (e.g. MP1906DS-Z).  
 For RoHS compliant packaging, add suffix -LF (e.g. MP1906DS-LF-Z)

## PACKAGE REFERENCE



### ABSOLUTE MAXIMUM RATINGS <sup>(1)</sup>

Input Voltage $V_{CC}$ .....	-0.3V to +18V
Voltage on SW $V_{SW}$ .....	-0.3V (-5V < 10ns) to +100V
Voltage on BT $V_{BT}$ .....	$V_{SW} + 18V$
Logic Inputs .....	-0.3 to ( $V_{CC} + 6.5V$ ), or 18.5V for $V_{CC} \geq 12V$
Continuous Power Dissipation ( $T_A = 25^\circ C$ ) <sup>(2)</sup>	1.4W
Junction Temperature .....	$-40^\circ C$ to $+150^\circ C$
Lead Temperature (Solder 10sec) .....	$260^\circ C$
Storage Temperature .....	$-55^\circ C$ to $+150^\circ C$

### Recommended Operating Conditions <sup>(3)</sup>

Input Voltage $V_{CC}$ .....	10V to 16V
Maximum Voltage on SW $V_{SW}$ .....	80V
Logic Inputs .....	0V to $V_{CC}$
Voltage slew rate on SW .....	< 50V/ns
PWM frequency .....	< 300kHz
Operating Junction Temp. ( $T_J$ ) .	$-40^\circ C$ to $125^\circ C$

Thermal Resistance <sup>(4)</sup>	$\theta_{JA}$	$\theta_{JC}$
SOIC8 .....	90 .....	45... $^\circ C/W$

#### Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature  $T_J$  (MAX), the junction-to-ambient thermal resistance  $\theta_{JA}$ , and the ambient temperature  $T_A$ . The maximum allowable continuous power dissipation at any ambient temperature is calculated by  $P_D$  (MAX) =  $(T_J$  (MAX) -  $T_A$ ) /  $\theta_{JA}$ . Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- 3) The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on JESD51-7, 4-layer PCB.

## ELECTRICAL CHARACTERISTICS

$V_{CC} = 12V$ ,  $V_{SW}=0V$ , no load on TG or BG,  $T_A = 25^\circ C$ , unless otherwise noted.

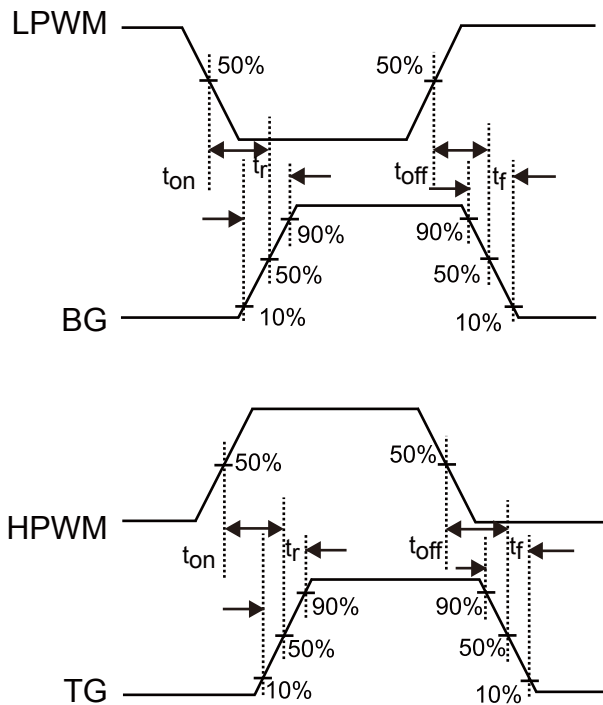
Parameter	Symbol	Condition	Min	Typ	Max	Units
<b>Supply Current</b>						
$V_{CC}$ quiescent current	$I_{CCQ}$	$V_{LPWM}=5V$ , $V_{HPWM}=0V$	70	90	110	$\mu A$
$V_{CC}$ operation current	$I_{CC}$	$f=50kHz$ , $C_{LOAD\ BG}=1nF$		0.9	1.5	mA
Bootstrap quiescent current	$I_{BTQ}$	$V_{LPWM}=5V$ , $V_{HPWM}=0V$		30		$\mu A$
Bootstrap operation current	$I_{BT}$	$f=50kHz$ , $C_{LOAD\ TG}=1nF$		0.7	1	mA
SW BT leakage current	$I_{LK}$	$V_{SW}=V_{BT}=80V$		0.1	0.5	$\mu A$
<b>Input</b>						
LPWM falling threshold	$V_{LPWMF}$				0.8	V
LPWM rising threshold	$V_{LPWMR}$		2.5			V
HPWM falling threshold	$V_{HPWMF}$				0.8	V
HPWM rising threshold	$V_{HPWMR}$		2.5			V
<b>Under-Voltage Protection (UVLO)</b>						
$V_{CC}$ rising threshold	$V_{CCTHR}$		8.2	8.8	9.4	V
$V_{CC}$ threshold hysteresis	$V_{CCTHH}$			0.7		V
Bootstrap rising threshold	$V_{BTTHR}$		4.5	5.5	6.5	V
Bootstrap threshold hysteresis	$V_{BTTHH}$			0.65		V
<b>Gate Driver Output</b>						
Low-side gate pull-up peak current <sup>(5)</sup>	$I_{BGU}$	$V_{BG}=0V$		350		mA
Low-side gate pull-down peak current <sup>(5)</sup>	$I_{BGD}$	$V_{BG}=12V$		1		A
High-side gate pull-up peak current <sup>(5)</sup>	$I_{TGU}$	$V_{TG}=0V$		350		mA
High-side gate pull-down peak current <sup>(5)</sup>	$I_{TGD}$	$V_{TG}=12V$		1		A
<b>Propagation Delays, Dead Times and Output Rising and Falling Times (<math>C_{Load}=1nF</math> cap) (please see timing diagram)</b>						
Turn-on propagation delay (TG)	$\tau_{ON\ TG}$	$V_{SW}=0V$		80	150	ns
Turn-off propagation delay (TG)	$\tau_{OFF\ TG}$	$V_{SW}=0V$		80	150	ns
Turn-on rise time (TG)	$\tau_{RISE\ TG}$			50	100	ns
Turn-off fall time (TG)	$\tau_{FALL\ TG}$			30	100	ns
Turn-on propagation delay (BG)	$\tau_{ON\ BG}$			80	150	ns
Turn-off propagation delay (BG)	$\tau_{OFF\ BG}$			80	150	ns
Turn-on rise time (BG)	$\tau_{RISE\_BG}$			50	100	ns
Turn-off fall time (BG)	$\tau_{FALL\_BG}$			30	100	ns
Deadtime, LS turn-off to HS turn-on & HS turn-on to LS turn-off	$\tau_{DT}$			150	250	ns

**ELECTRICAL CHARACTERISTICS(CONTIUUED)**
 $V_{CC} = 12V$ ,  $V_{SW}=0V$ , no load on TG or BG,  $T_A = 25^\circ C$ , unless otherwise noted.

Parameter	Symbol	Condition	Min	Typ	Max	Units
LPWM source current	$I_{LPWM}$	$I_{LPWM}=5V$	-8	-3	-1	$\mu A$
HPWM sink current	$I_{HPWM}$	$I_{HPWM}=5V$	1	3	8	$\mu A$
<b>Floating Gate Driver</b>						
BG-output-low to GND	$V_{BGL}$	$I_{BG}=100mA$		0.4	0.7	V
BG-output-high to rail	$V_{BGH}$	$I_{BG}=-100mA$ , $V_{BGH}=V_{CC}-V_{BG}$		1.5	1.7	V
TG-output-low to SW	$V_{TGL}$	$I_{TG}=100mA$		0.4	0.7	V
TG-output-high to rail	$V_{TGH}$	$I_{TG}=-100mA$ , $V_{TGH}=V_{CC}-V_{TG}$		1.5	1.7	V
<b>Switching Specifications</b>						
Minimum input pulse width to change the output <sup>(5)</sup>	$\tau_{PWM\_min}$				50	ns

**Notes:**

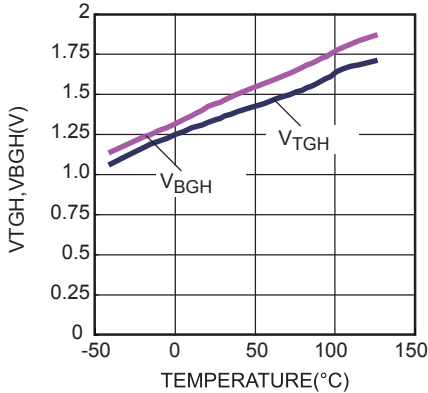
5) Guaranteed by design


**Figure 1: Gate Driver Timing Diagram**

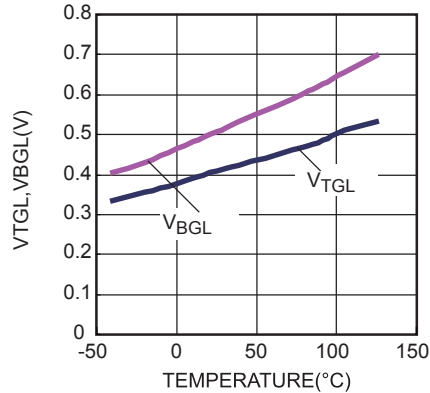
## TYPICAL CHARACTERISTICS

$V_{DD}=12V$ ,  $V_{SW}=0V$ ,  $T_A=+25^{\circ}C$ , unless otherwise noted.

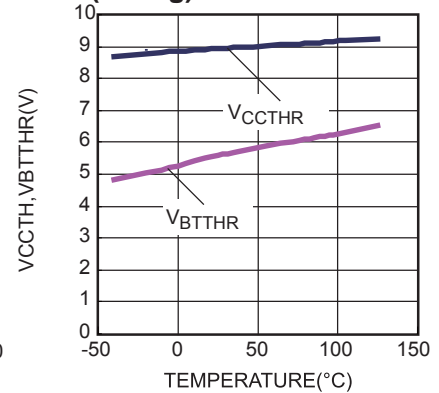
**High Level Output Voltage vs. Temperature**



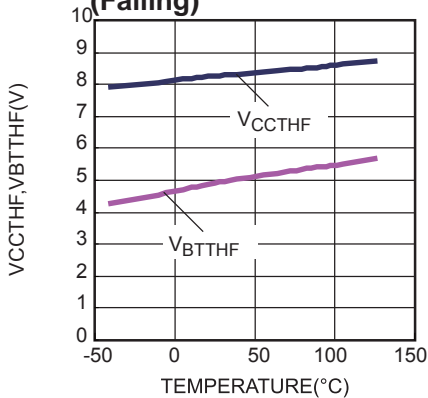
**Low Level Output Voltage vs. Temperature**



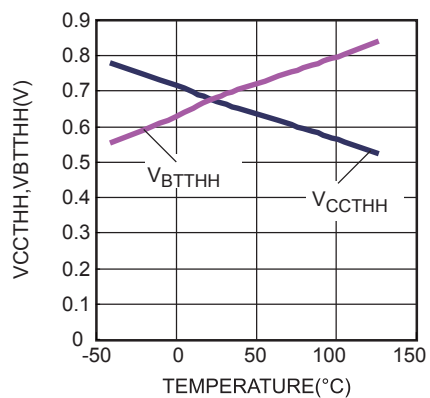
**Undervoltage Lockout Threshold vs. Temperature (Rising)**



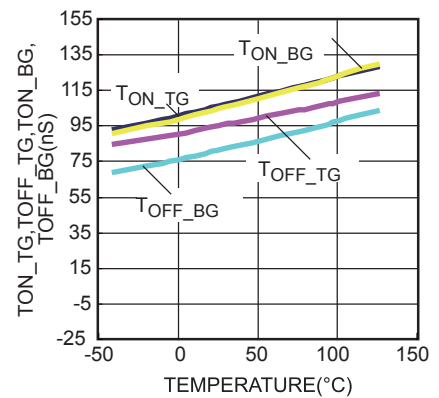
**Undervoltage Lockout Threshold vs. Temperature (Falling)**



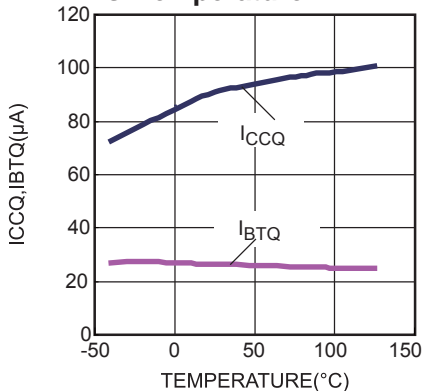
**Undervoltage Lockout Hysteresis vs. Temperature**



**Propagation Delay vs. Temperature**



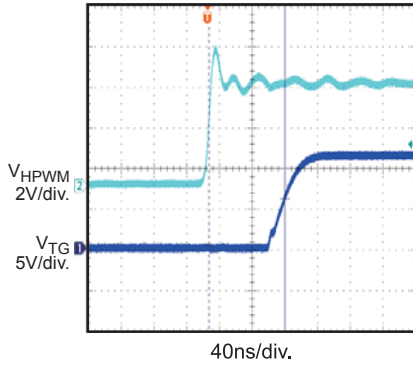
**Quiescent Current vs. Temperature**



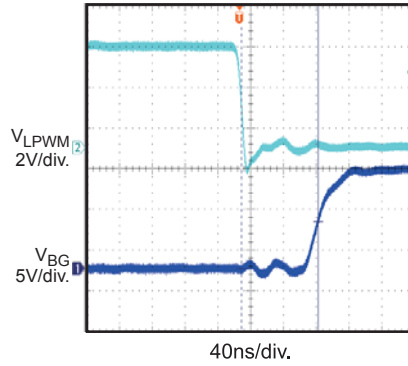
**TYPICAL PERFORMANCE CHARACTERISTICS**

$V_{CC} = 12V$ ,  $V_{SW} = 0V$ , 1nF load on TG and BG,  $T_A = 25^\circ C$ , unless otherwise noted.

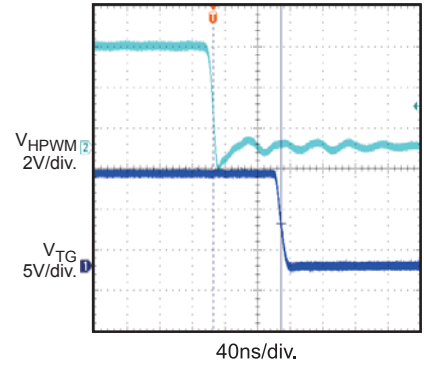
**Turn-on Propagation Delay**



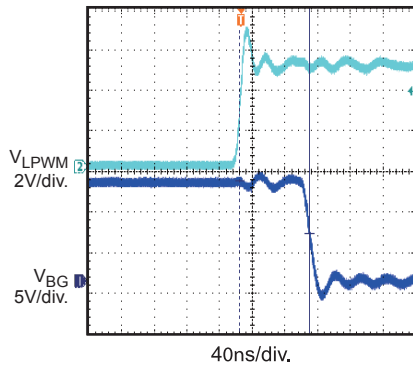
**Turn-on Propagation Delay**



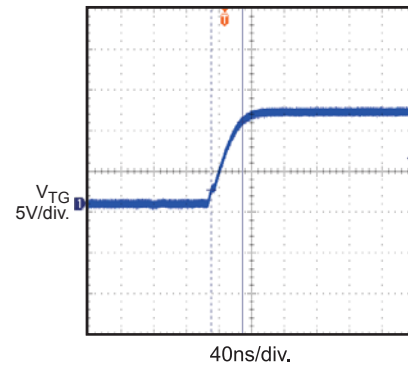
**Turn-off Propagation Delay**



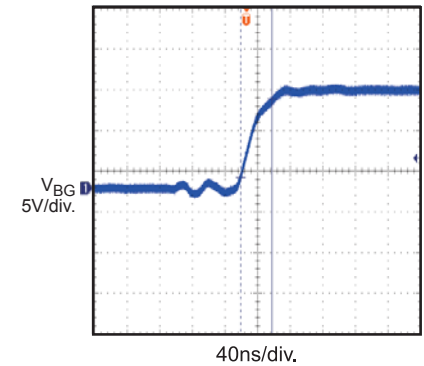
**Turn-off Propagation Delay**



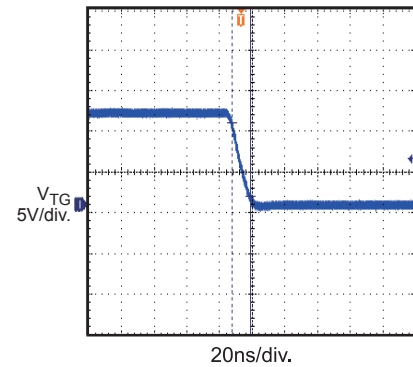
**Drive Rise Time(1nF Load)**



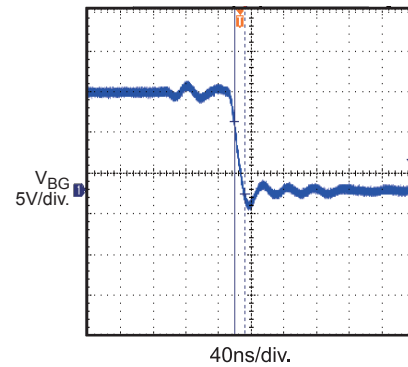
**Drive Rise Time(1nF Load)**



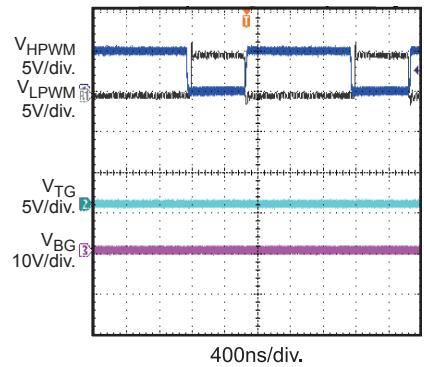
**Drive Fall Time(1nF Load)**



**Drive Fall Time(1nF Load)**



**Input Signal Overlap Protection**



## PIN FUNCTIONS

Pin #	Name	Description
1	VCC	Supply Input. Supplies power to all internal circuitry. Requires a decoupling capacitor to ground placed close to this pin to ensure a stable and clean supply.
2	HPWM	Logic input for high-side gate driver output.
3	LPWM	Logic input for low-side gate driver output. Active low.
4	GND	Ground.
5	BG	Gate Driver Output for low-side MOSFET.
6	SW	Source Return for high-side MOSFET.
7	TG	Gate Driver Output for high-side MOSFET.
8	BT	Bootstrap. Internal power supply pin for high-side floating driver. Add a 1 $\mu$ F ceramic bootstrap capacitor from BT to SW pin.

FUNCTIONAL BLOCK DIAGRAM

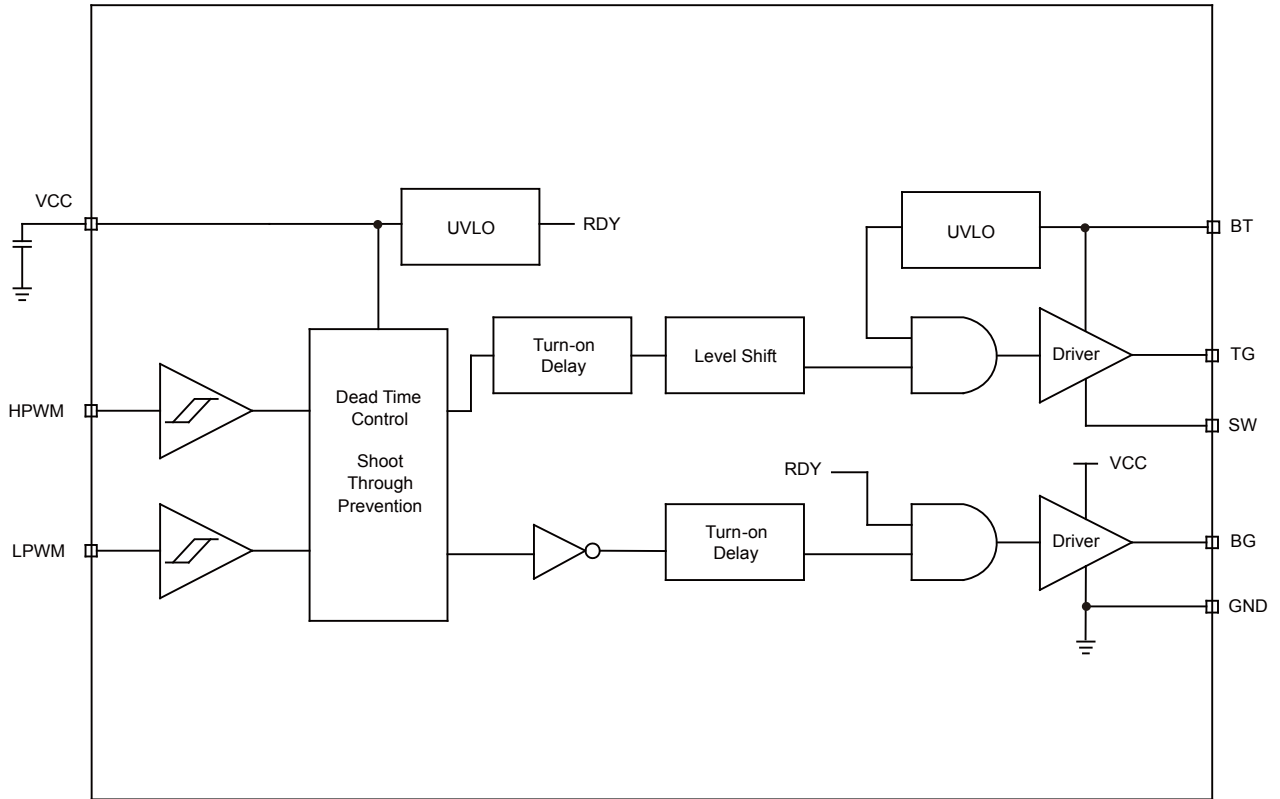


Figure 2: Functional Block Diagram



**OPERATION**

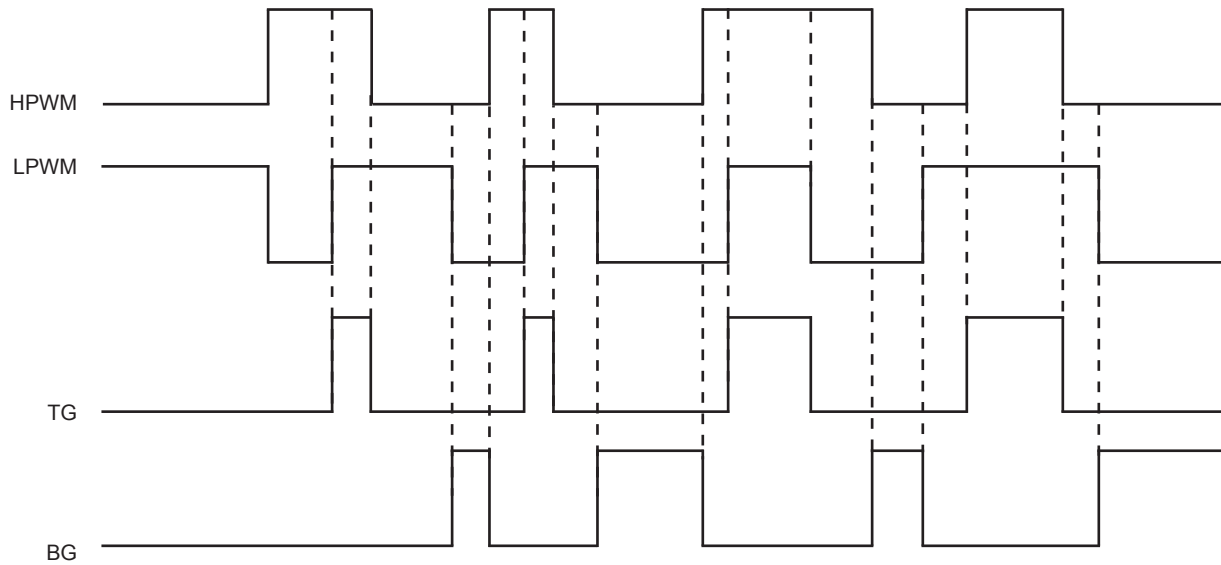
**Switch Shoot-through Protection**

The input signals of HPWM and LPWM are independently controlled. Input shoot-through protection circuitry prevents shoot-through between the TG and BG outputs. Only one of the FET drivers can be on at one time. If HPWM is high and LPWM is low, both TG and BG are OFF.

**Under Voltage Lockout**

When  $V_{CC}$  or  $V_{BT}$  goes below their respective UVLO threshold, both BG and TG outputs will go low to both FETS. Once  $V_{CC}$  and  $V_{BT}$  rises above the UVLO threshold, both TG and BG will stay low until there is a rising edge on either HPWM or LPWM.

Figure 3 shows the operation of the TG and BG under different HPWM and LPWM and UVLO conditions.



**Figure 3: Input/Output Timing Diagram**

## APPLICATION INFORMATION

### Reference Design Circuits Half Bridge Motor Driver

In a half-bridge converter topology, the MOSFET-driving signals have a dead time: HPWM and LPWM driven with alternating signals from the

PWM controller. The input voltage can be up to 80V in this application.

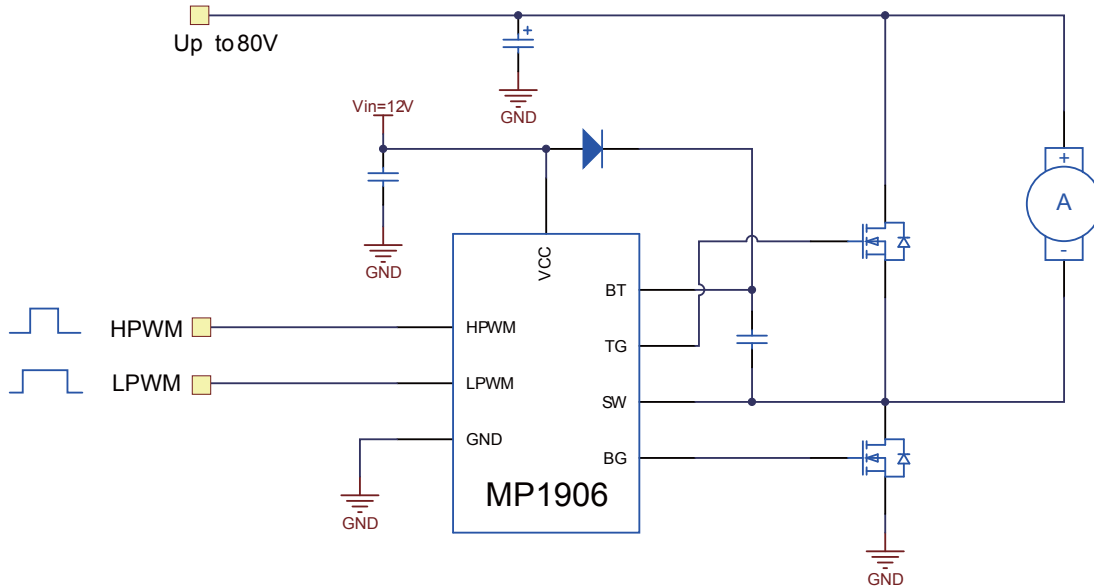


Figure 4: Half-Bridge Motor Driver

### Active-Clamp-Forward Converter

An active-clamp-forward-converter topology alternately drives the MOSFETs. The high-side MOSFET and the capacitor,  $C_{RESET}$ , reset the

power transformer in a lossless manner. This topology runs well at duty cycles exceeding 50%. However, the input voltage may not run at 80V.

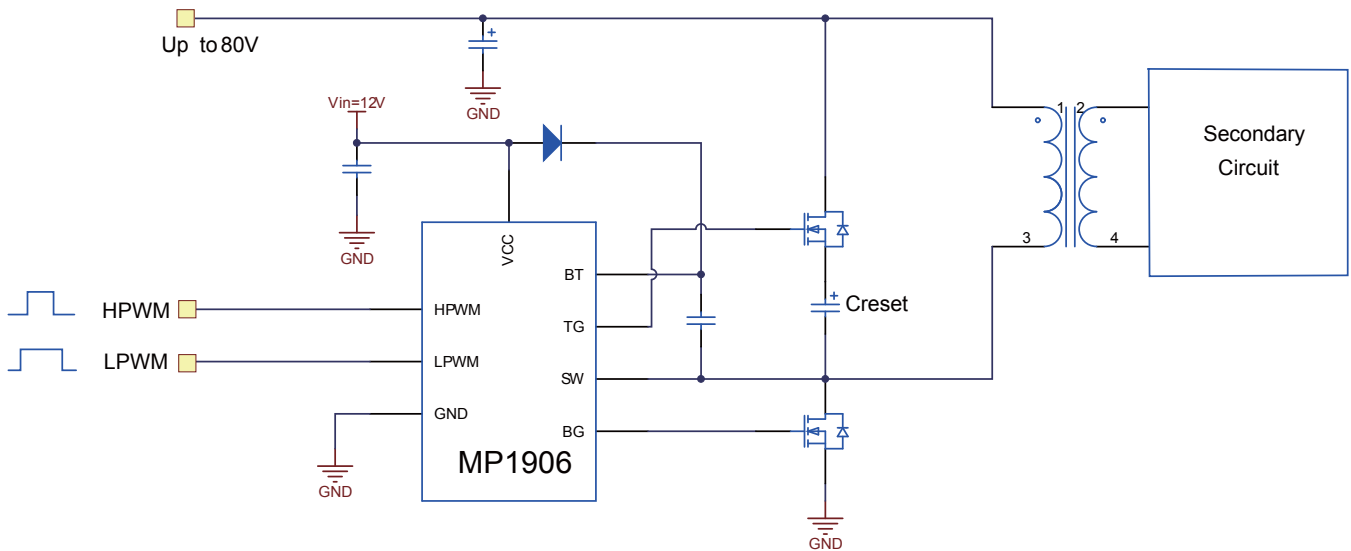
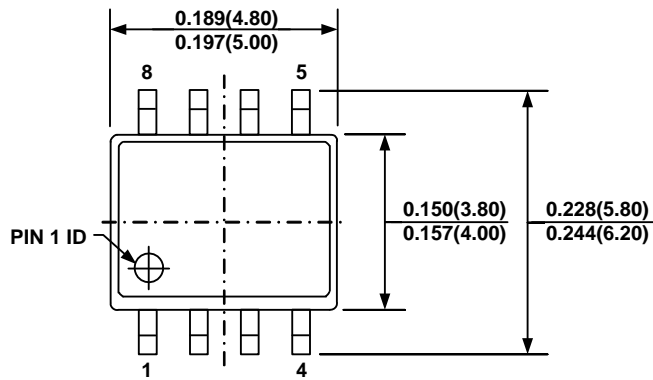


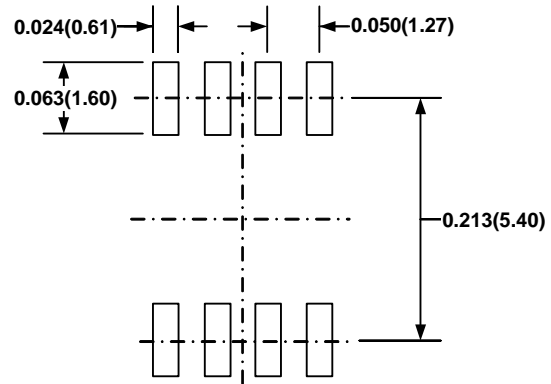
Figure 5: Active-Clamp Forward Converter

## PACKAGE INFORMATION

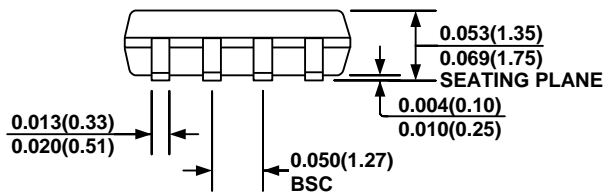
### SOIC8



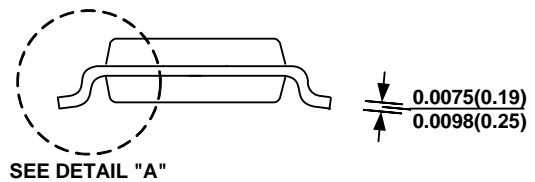
**TOP VIEW**



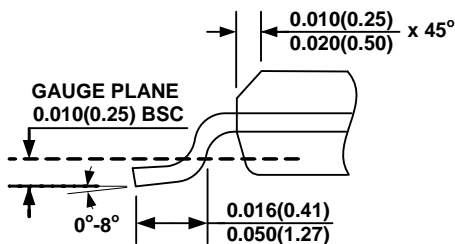
**RECOMMENDED LAND PATTERN**



**FRONT VIEW**



**SIDE VIEW**



**DETAIL "A"**

**NOTE:**

- CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
- PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
- LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
- DRAWING CONFORMS TO JEDEC MS-012, VARIATION AA.
- DRAWING IS NOT TO SCALE.

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